

HAN Electronic Components

12-Channel Multi-Display LED Driver with Integrated LDOs and illumination

BD6081GU BD6081GVW

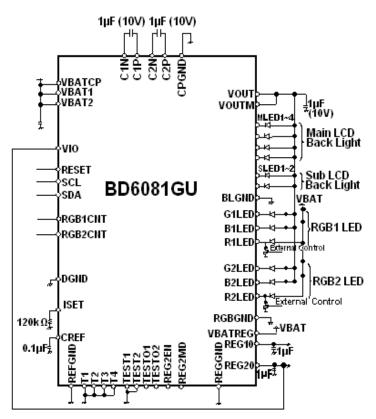
General Description

BD6081GU / BD6081GVW is compound LED Driver which is the most suitable for the cellular phone. Main LCD Back Light LED Driver (Max 4 Light), Sub LCD Back Light LED Driver (Max 2 Light), 2 system RGB LED Drivers, 2Ch LDO (2.8V/1.8V) included. This is PMIC (Power Management IC) that is the most suitable for "the indication part" of the cellular phone. A charge pump form is adopted, and a coil is never used for the part DC/DC. This IC achieves compact size with the chip size package (VCSP85H3). [BD6081GU] This IC solves a mounting problem by BGA package (SBGA063W060). [BD6081GVW]

Features

- Main LCD Back Light LED Driver (Max 4 Light) 4 Lighting / 3 Lighting can be chosen (register setting)
- Sub LCD Back Light LED Driver (Max 2 Light)
 2 Lighting / 1 Lighting can be chosen (register setting)
- RGB LED Driver (2 System) Slope control is built in.(2 system independence can be controlled.) LED connection (for G1LED,G2LED,B1LED, B2LED) can be set up in the battery or the DC/DC output.(register setting) LED connection (for R1LED,R2LED) can be set up in the battery only.

Typical Application Circuit



- 2ch Series Regulator
 1.8V output low current consumption mode / normal mode Switching is possible.
 (The outside pin control / register setting)
- Charge Pump DC/DC
 Soft start Functions
 Over voltage protection (Auto-return type)
 Over current protection (Auto-return type)
- Thermal shutdown (Auto-return type)
 I²C BUS Fast-mode (max 400kHz)Writing

Key Specifications

- Operating power supply voltage range: 2.7V to 5.5V
- LED maximum setup current1: 32mA (Max.) LED maximum setup current2: 31.5mA (Max.)
- Oscillator frequency: 1.0 MHz(Typ.)
- Operating temperature range: -25 to +85
 Output Voltage (REG1): 2.8V(Tvp.)
- Output Voltage (REG1):
 Output Voltage (REG2):
 - Output Voltage (REG2): 1.8V(Typ.)

Packages

SBGA063W060 VCSP85H3 W(Typ.) x D(Typ.) x H(Max.) 6.00mm x 6.00mm x 0.90mm 3.90mm x 3.90mm x 1.00mm

Product structure : Silicon monolithic integrated circuit This product is not designed protection against radioactive rays

Pin Configurations [Bottom View]

BD6081GU

E G1LED B1LED ISET REG2EN RGB2CNT SDA DGND D RGBGND R2LED TEST11 TEST12 SCL VOUTM VOUT C G2LED B2LED O TEST02 TEST01 C1P C2P		1	2	3	4	5	6	7
FREFGNDR1LEDCREFREG10REG2MDRGB1CNTRESETEG1LEDB1LEDISETREG2ENRGB2CNTSDADGNDDRGBGNDR2LEDTEST11TEST12SCLVOUTMVOUTCG2LEDB2LEDOriginal indexTEST02TEST01C1PC2P	Α	T1	SLED2	MLED1	MLED3	VBAT2	C2N	T2
F REFGND R1LED CREF REG10 REG2MD RGB1CNT RESET E G1LED B1LED ISET REG2EN RGB2CNT SDA DGND D RGBGND R2LED TEST11 TEST12 SCL VOUTM VOUT C G2LED B2LED O TEST02 TEST01 C1P C2P	в	SLED1	BLGND	MLED2	MLED4	CPGND	C1N	VBATCP
F REFGND R1LED CREF REG10 REG2MD RGB1CNT RESET E G1LED B1LED ISET REG2EN RGB2CNT SDA DGND	С	G2LED	B2LED	•	TESTO2	TESTO1	C1P	C2P
F REFGND R1LED CREF REG10 REG2MD RGB1CNT RESET	D	RGBGND	R2LED	TESTI1	TESTI2	SCL	VOUTM	VOUT
	Е	G1LED	B1LED	ISET	REG2EN	RGB2CNT	SDA	DGND
G T4 VBAT1 REG20 VBATREG REGGND VIO T3	F	REFGND	R1LED	CREF	REG10	REG2MD	RGB1CNT	RESET
	G	T4	VBAT1	REG2O	VBATREG	REGGND	VIO	Т3

Total: 48ball There is no Ball only in C3 for index.

н	Т2	C1P	C2P	-	-	SDA	RESET	тз
G	C1N	-	-	VOUTM	TESTO1	SCL	RGB2CNT	VIO
F	CPGND	C2N	TESTI1	VOUT	DGND	RGB1CNT	TESTO2	REG2MD
Е	MLED3	MLED4	VBAT2	VBATCP	-	REG2EN	REGGND	-
D	MLED2	-	MLED1	-	-	REG10	VBATREG	-
С	(index)	BLGND	B2LED	-	-	TESTI2	CREF	REG2O
в	SLED2	SLED1	R2LED	-	-	REFGND	-	VBAT1
Α	T1	G2LED	RGBGND	B1LED	B1LED G1LED		ISET	T4
	1	2	3	4	5	6	7	8

BD6081GVW

Total: 63ball There is no Ball only in C1 for index. "-" means NC pin (Non connect to internal circuit)

Figure 2. Pin Configuration of BD6081GVW

Absolute Maximum Ratings (Ta=25)

Parame	ter	Symbol	Ratings	Unit
Maximum Applied volta	ige	VMAX	7	V
Dower Dissipation	BD6081GU	Pd	1725 note1)	mW
Power Dissipation	BD6081GVW	Pd	1060 note2)	mW
Operating Temperature	Range	Topr	-25 to +85	
Storage Temperature F	Range	Tstg	-55 to +150	

Note1)Power dissipation deleting is 13.8mW/ , when it's used in over 25 .

(It's deleting is on the board that is ROHM's standard))

Note2)Power dissipation deleting is 8.48mW/ , when it's used in over 25 .

(It's deleting is on the board that is ROHM's standard))

Recommended Operating Ratings (VBAT≥VIO, Ta=-25 to 85)

Parameter	Symbol	Ratings	Unit
VBAT input voltage	VBAT	2.7 to 5.5	V
VIO pin voltage	VIO	1.65 to 3.3	V

Figure 1. Pin Configuration of BD6081GU

Electrical Characteristics (Unless otherwise specified, Ta=25 , VBAT=3.6V, VIO=1.8V)

ParameterSymbolImageUnitConditionICircuit current 1HBAT101.43.0 $\mu\Lambda$ RESET=0V, VIO=0VVBAT Circuit current 2HBAT200.53.0 $\mu\Lambda$ RESET=0V, VIO=0VVBAT Circuit current 3IBAT3-6.29.5 $\mu\Lambda$ REG2 low current consumption mode, loo-0mAVBAT Circuit current 4HBAT6-100150 $\mu\Lambda$ REG2 nomal mode, loo-0mAVBAT Circuit current 5HBAT6-140210 $\mu\Lambda$ REG2 nomal mode, loo-0mAVBAT Circuit current 6HBAT6-126188mADC/DC xt mode, loo-0mA,VBAT Circuit current 7IBAT6-126188mADC/DC xt mode, loo-0mA, VBAT=2.7VVBAT Circuit current 8IBAT8-126188mADC/DC xt mode, loo-0mA, VBAT=2.7VLED Driver 1-32MAMLED1 to 4, SLED1 to 2LED current Step 2ILEDSTP1-32RTLED current Step 2ILEDXT9-32MARILED, GILED, BILED, RZLED,LED current accurateILED182022mARIED1 to 4, SLED1 to 2, SET=120kDLED current datchingILED182022mARIED of ILED, SILED, S				,	,		
LCincuit current 1 IBAT1 - 0.1 3.0 μA RESET=0V, VIO=0V VBAT Circuit current 2 IBAT2 - 0.5 3.0 μA RESET=0V, VIO=0V VBAT Circuit current 3 IBAT3 - 6.2 9.5 μA RESET=0V, VIO=1.8V VBAT Circuit current 4 IBAT5 - 140 210 μA REG2 roomal mode, Io=0mA VBAT Circuit current 5 IBAT5 - 140 210 μA REG1, REG2 normal mode, Io=0mA VBAT Circuit current 6 IBAT6 - 63 95 mA DC/DC xt1.5mode, Io=0mA, VBAT=2.7V LED truent 7 IBAT7 - 95 143 mA DC/DC xt1.5mode, Io=60mA, VBAT=2.7V LED current 8tep1 LEDSTP1 - 32 MA MLED1 to 4, SLED1 to 2 LED current Step1 LEDSTP1 - 32 mA MLED1 to 4, SLED1 to 2 LED dwinum setup current 2 IMAX1 - - 31.5 mA MLED1 to 4, SLED1 to 2, SLED,	Parameter	Symbol	Min.		Max.	Unit	Condition
VBAT Circuit current 1 IBAT1 . 0.1 3.0 µA RESET=0V, VIO=18V VBAT Circuit current 3 IBAT2 . 0.5 3.0 µA RESET=0V, VIO=18V VBAT Circuit current 3 IBAT3 . 6.2 9.5 µA REG2 low current consumption mode, lo=0mA VBAT Circuit current 4 IBAT6 . 140 210 µA REG1, REG2 normal mode, lo=0mA VBAT Circuit current 6 IBAT6 . 63 95 mA DC/DC x1mode, lo=0mA, VBAT=4.0V VBAT Circuit current 7 IBAT7 . 95 143 mA DC/DC x1mode, lo=60mA, VBAT=2.7V VBAT Circuit current 8 IBAT8 . 125 188 mA DC/DC x1mode, lo=60mA, VBAT=2.7V LED current Step1 ILEDSTP1 32 Step MLED1 to 4, SLED1 to 2, RTLED, G1LED, B1LED, R2LED, G2LED, B2LED (wB MAT setting) LED durinent Maching ILED 18 20 22 mA ILED-20mA, SET=120kQ LED current Matching ILED 1 1 9 Settive	[Circuit Current]			.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	man		
VBAT Circuit current 3 IBAT3 · 6.2 9.5 µA REG2 normal mode, lo=0mA lo=0mA VBAT Circuit current 4 IBAT4 · 100 150 µA REG2 normal mode, lo=0mA VBAT Circuit current 5 IBAT6 · 140 210 µA REG2 normal mode, lo=0mA VBAT Circuit current 7 IBAT6 · 163 95 mA DC/DC x1mode, lo=60mA,VBAT=3.0V VBAT Circuit current 7 IBAT8 · 125 188 mA DC/DC x1mode, lo=60mA,VBAT=2.7V LED current Step1 ILEDSTP1 · · Step MLED1 to 4, SLED1 to 2 LED current Step1 ILEDSTP1 · · Step R1LED, G1LED, B1LED,RLED, G2LED, B2LED, B1LED,RLED, LED dawinum setup current 2 IMAX2 · · 31.5 mA MLED1 to 4, SLED1 to 2, ISET=120KO LED current Matching ILED 18 20 22 mA ILED2 ONLOSTET=20KO LED current Matching ILED 18 20 22 mA ILED to 4, SLED1 to 2, ISET=120KO<		IBAT1	-	0.1	3.0	μA	RESET=0V, VIO=0V
VBA1 Circuit current 4 IBA13 - 5.2 9.5 IµA Ine=mA VBAT Circuit current 5 IBAT5 - 140 150 µA REG2 normal mode, Io=0mA VBAT Circuit current 6 IBAT5 - 140 PA REG1, REG2 normal mode, Io=0mA VBAT Circuit current 7 IBAT5 - 63 95 mA DC/DC x1mode, Io=60mA,VBAT=4.0V VBAT Circuit current 8 IBAT8 - 125 188 mA DC/DC x1mode, Io=60mA,VBAT=2.7V LED Driver J - 125 188 mA DC/DC x2 mode, Io=60mA,VBAT=2.7V LED current Step1 ILEDSTP1 - 32 mA MLED1 to 4, SLED1 to 2 LED durient Step1 ILEDSTP1 - 32 mA MLED1 to 4, SLED1 to 2, ISET=120kD LED durient accurate ILED 18 20 22 mA MLED1 to 4, SLED1 to 2 LED current Accurate ILED 18 20 22 mA RILE0, SILED, SILED, SILED, SILED, SILED, SILED, SILED, SILED, SILED, SILED	VBAT Circuit current 2	IBAT2	-	0.5	3.0	μA	RESET=0V, VIO=1.8V
VBAT Circuit current 5 IBAT5 - 140 210 μA REG1, REG2 normal mode, Io=0mA VBAT Circuit current 6 IBAT6 - 63 95 mA DC/DC x1mode, Io=0mA, VBAT=4.0V VBAT Circuit current 7 IBAT7 - 95 143 mA DC/DC x1 smode, Io=60mA, VBAT=3.0V VBAT Circuit current 8 IBAT8 - 125 188 mA DC/DC x2 mode, Io=60mA, VBAT=2.7V LED Driver J - - Step MLED1 to 4, SLED1 to 2 REG1, REG2, normal mode, Io=60mA, VBAT=2.7V LED current Step1 ILEDSTP - Step MLED1 to 4, SLED1 to 2 REF120K0 LED durinent seque current 1 IMAX1 - - 32 mA MLED1 to 4, SLED1 to 2, ISET=120K0 LED durinent accurate ILED 18 20 22 mA Returent A, SLED, (with mAs setting) LED current accurate ILED 18 20 22 mA Returent A, SLED, (s1ED, RALED, RALED	VBAT Circuit current 3	IBAT3	-	6.2	9.5	μA	•
VBAT Circuit current 6 IBAT6 - 63 95 mA DC/DC x1mode, lo=60mA,VBAT=4.0V VBAT Circuit current 7 IBAT7 - 95 143 mA DC/DC x15mode, lo=60mA,VBAT=3.6V VBAT Circuit current 8 IBAT8 - 125 188 mA DC/DC x15mode, lo=60mA,VBAT=2.7V ILED current Step1 ILEDSTP2 - Step MLED1 to 4, SLED1 to 2 LED current Step2 ILEDSTP2 - Step R1LED, G1LED, B1LED,R2LED, G2LED, B2LED (with 0mA setting) LED Maximum setup current 2 IMAX2 - - 31.5 mA MLED1 to 4, SLED1 to 2, ISET=120kQ LED durrent accurate ILED 18 20 22 mA ILED, OILED, B1LED,R2LED, ISET=120kQ LED current Matching ILEDMT - 5 31.5 mA Between MLED1 to 4 Between MLED1 to 2 LED OFF Leak current ILKLED - - 1.0 μA IDC/DC(Charge Pump) - - 255 mA VBAT≥3.2V, VOUT=4V Detween R2LED, G2LED and B2LED C	VBAT Circuit current 4	IBAT4	-	100	150	μA	REG2 normal mode, Io=0mA
VBAT Circuit current 7IBAT7.95143mADC/DC x1 5mode, Io=60mA,VBAT=3.6VVBAT Circuit current 8IBAT8.125184mADC/DC x2 mode, Io=60mA,VBAT=2.7VLED Driver J32StepMLED1 to 4, SLED1 to 2LED current Step1ILEDSTP2 32 StepR1LED, G1LED, 81LED, R2LED, (S2LED, B2LED) (with OmA setting)LED Maximum setup current 1IMAX132mALED durrent sep2ILEDTP2R1LED, G1LED, 81LED, R2LED, (S2LED, B2LED) (with OmA setting)LED Maximum setup current 2IMAX231.5mALED current accurateILED182022mAILED-20mA, ISET=120kQLED current MatchingILEDMT1.0 μA LED OFF Leak currentILKLED1.0 μA CUC/CCCArge Pump)VY1 is LED forward voltageOutput voltageVoCPVI+0.5VI+0.2.VVVIs LED forward voltageOver voltage protection detect voltageOver current protection detect voltageVoltage differenceVsat1Voltage differenceVsat1	VBAT Circuit current 5	IBAT5	-	140	210	μA	REG1, REG2 normal mode, Io=0mA
VBAL Circuit current 7 IBA17 - 95 143 mA Io=60mA,VBAT=3.6V VBAT Circuit current 8 IBA78 - 125 188 mA DC/DC x2 mode, Io=60mA,VBAT=3.7V LED Driver J - 32 Step MLED1 to 4, SLED1 to 2 LED current Step1 ILEDSTP1 - 32 MA MLED1 to 4, SLED1 to 2, SLED1	VBAT Circuit current 6	IBAT6	-	63	95	mA	
LED Driver J LED current Step1 LEDSTP1 32 Step MLED1 to 4, SLED1 to 2, G2LED, G1LED, B1LED, R2LED, G2LED, B2LED (with 0mA setting) LED darimum setup current 1 IMAX1 - - 32 mA MLED1 to 4, SLED1 to 2, ISET=120kQ LED Maximum setup current 2 IMAX2 - 31.5 mA MLED1 to 4, SLED1 to 2, ISET=120kQ LED Maximum setup current 2 IMAX2 - 31.5 mA RILED, G1LED, B1LED, R2LED, G2LED, B2LED, ISET=120kQ LED current accurate ILED 18 20 22 mA ILED20mA, ISET=120kQ LED current Matching ILEDMT - 5 10 % Between RLED1 to 4 LED current Matching ILEDMT - 5 10 % Between R2LED, G2LED and B1LED BEtween R2LED, G2LED and B2LED LED COFC(Charge Pump)T Output voltage VOCP VI+0.15 VI+0.2 - V V1 is LED forward voltage Current Load IOUT - 255 MA VBAT=3.2V, VOUT=4V Over outrage protection detect current OVP - 6	VBAT Circuit current 7	IBAT7	-	95	143	mA	
LED current Step1 ILEDSTP1 32 Step MLED1 to 4, SLED1 to 2 LED current Step2 ILEDSTP2 64 Step R1LED, G1LED, B1LED, R1LED, R		IBAT8	-	125	188	mA	DC/DC x2 mode, Io=60mA,VBAT=2.7V
LED current Step2 ILEDSTP2 64 Step R1LED, G1LED, B1LED, R2LED, G2LED, B2LED, with GMA setting) LED Maximum setup current 1 IMAX2 - - 32 mA MLED1 to 4, SLED1 to 2, ISET=120kQ LED Maximum setup current 2 IMAX2 - - 31.5 mA RLED, G1LED, B1LED, R2LED, G2LED, B2LED, ISET=120kQ LED current accurate ILED 18 20 22 mA ILED_common setup current 2 LED current accurate ILED 18 20 22 mA ILED, ISET=120kQ LED current Matching ILED 18 20 2 mA ILED=20mA, ISET=120kQ LED current Matching ILED - - 1.0 µA Between RLED1 to 4 DC/DC(Charge Pump)T - - 0 µA VBAT23.2V, VOUT=4V Over current protection detect voltage VOVP - 6.0 6.5 V VOUT=0V Current tordection detect voltage VO1 2.716 2.80 2.84 V Ice150mA, VBAT23.1V <t< td=""><td>【LED Driver】</td><td></td><td></td><td></td><td></td><td></td><td></td></t<>	【LED Driver】						
LED current Step2LEDS 1/2Image of the set o	LED current Step1	ILEDSTP1		32		Step	
LED Maximum setup current 2IMAX231.5mAR1LED, G1LED, B1LED, R2LED, G2LED, ISET=120kQLED current accurateILED182022mAILED=20mA, ISET=120kQLED current MatchingILEDMT510 $\%$ Between MLED to 4LED current MatchingILEDMT1.0 μ ABetween R1LED, G1LED and B1LEDLED OFF Leak currentILKLED1.0 μ ABetween R1LED, G1LED and B1LEDDufput voltageVoCPVf+0.15Vf+0.2.VVf is LED forward voltageCurrent LoadIOUT255mAVBAT>3.2V, VOUT=4VOscillator frequencyfosc0.81.01.2MHzOver voltage protection detect voltageOVP.6.06.5VOver current protection detect currentOCP.250375mAVOUT=0VIVO voltage differenceVsat1.0.20.3VVBAT=2.5V, Io=150mAIOvaldage differenceVsat1.0.060mVVBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo12.1.060mNVeBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo11.1.060mNVeBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo21.1.060mVVeT=3.2 to 5.5V, Io=150mAInput stability Δ Vo21.1.060mVVeT=3.2 to 5.5	LED current Step2	ILEDSTP2		64		Step	
LED Maxmum setup current 2IMA2··31.5IMAG2LED, B2LED, ISET=120kΩLED current accurateILED182022mAILED-20mA, ISET=120kΩLED current MatchingILEDM-510WABetween MLED1 to 4LED current MatchingILKLED-1.0µABetween R2LED, G2LED and B1LED Between R2LED, G2LED and B1LED Between R2LED, G2LED and B1LEDLED OFF Leak currentILKLED-1.0µAIDC/DC(Charge Pump)1.0µAOutput voltageVoCPVI+0.15VI+0.2-VV Is LED forward voltageCurrent LoadIOUT255mAVBAT23.2V, VOUT=4VOscillator frequencyfosc0.81.01.2MHzOver voltage protection detect voltageOVP-6.06.5VOutput voltageVo12.7162.802.884VIo=150mA, VBAT23.1VIV voltage differenceVsat1-0.20.3VVBAT=3.2 to 5.5V, Io=150mAInput sabilityΔVo11-1060mVVBAT=3.2 to 5.5V, Io=150mAInput sabilityΔVo12-1.01.5KΩIteres-1.01.5KΩIo=150mAInput sabilityΔVo211.741.881.89VIo=150mAInput voltage 1Vo211.741.881.89VIo=150mAInput sabilityΔVo221.71	LED Maximum setup current 1	IMAX1	-	-	32	mA	
LED current MatchingILEDMT-510%Between NLED1 to 4 Between SLED1 to 2 Between SLED1 to 2 Between SLED1 to 2 Between R1LED, G1LED and B1LED Between R1LED, G1LED and B1LED modelLED OFF Leak currentILKLED1.0µAIDC/DC(Charge Pump)]2.5MAVBAT23.2V, VOUT=4VOutput voltageVoCPVf+0.15Vf+0.2-VVf is LED forward voltageCurrent LoadIOUT255MAVBAT23.2V, VOUT=4VOscillator frequencyfosc0.81.01.2MHzOver voltage protection 	LED Maximum setup current 2	IMAX2	-	-	31.5	mA	G2LED, B2LED, ISET=120kΩ
LED current MatchingILEDMT	LED current accurate	ILED	18	20	22	mA	
LED OFF Leak currentILKLED··1.0μAIDC/DC(Charge Pump)]Output voltageVoCPVf+0.15Vf+0.2·VVf is LED forward voltageCurrent LoadIOUT··255mAVBAT≥3.2V, VOUT=4VOscillator frequencyfosc0.81.01.2MHzOver voltage protection detect voltageOVP·6.06.5VOver current protection detect currentOCP·250375mAVOUT=0VIREG1··2.884VIo=150mA, VBAT≥3.1VOver durge differenceVo12.7162.802.884VIo=150mA, VBAT≥3.1VI/O voltage differenceVo31·0.20.3VVBAT=2.5V, Io=150mAInput stabilityΔV012·1060mVIo=1 to 150mAInput stabilityΔV012·1.01.5kΩIo=1 to 140Short circuit current limitIlim01·1.5kΩIo=150mAOutput voltage 1Vo211.741.881.86VIo=150mAOutput voltage 2Vo221.711.81.89VIo=100µAInput stabilityΔV021·1.0160mVIo=100µAInput stabilityΔV021·1.0160mVIo=100µAInput stabilityΔV021·1.0160mVIo=100µAInput stabilityΔV021·1.01 <t< td=""><td>LED current Matching</td><td>ILEDMT</td><td>-</td><td>5</td><td>10</td><td>%</td><td>Between SLED1 to 2 Between R1LED, G1LED and B1LED</td></t<>	LED current Matching	ILEDMT	-	5	10	%	Between SLED1 to 2 Between R1LED, G1LED and B1LED
Output voltage VoCP Vf+0.15 Vf+0.2 - V V fis LED forward voltage Current Load IOUT - 255 mA VBAT≥3.2V, VOUT=4V Oscillator frequency fosc 0.8 1.0 1.2 MHz Over voltage protection detect voltage OVP - 6.0 6.5 V Over current protection detect current OCP - 250 375 mA VOUT=0V IREG1 0CP - 250 375 mA VOUT=0V IReg1 0.2 0.3 V Isentant, VBAT≥3.1V VI/1 I/O voltage difference Vsat1 - 0.2 0.3 V VBAT=2.5V, Io=150mA Load stability ΔV012 - 10 60 mV Io=1 to 150mA Input stability ΔV012 - 10 60 mV VBAT=3.2 to 5.5V, Io=150mA Ripple Rejection Ratio RR1 30 40 - dB f=100	LED OFF Leak current	ILKLED	-	-	1.0	μA	,,
Current LoadIOUT255mAVBAT≥3.2V, VOUT=4VOscillator frequencyfosc0.81.01.2MHzOver voltage protection detect voltage OVP -6.06.5VOver current protection detect current OCP -250375mAVOUT=0VIREG1 OCP -250375mAVOUT=0VOutput voltageVo12.7162.802.884VIo=150mA, VBAT≥3.1VI/O voltage differenceVsat1-0.20.3VVBAT=2.5V, Io=150mALoad stability $\Delta Vo11$ -1060mVIo=1 to 150mAInput stability $\Delta Vo12$ -1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR13040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim01-225450mAVo=0VOutput voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA 	【DC/DC(Charge Pump)】						
Oscillator frequencyfosc0.81.01.2MHzOver voltage protection detect voltageOVP-6.06.5VOver current protection detect currentOCP-250375mAVOUT=0VIREG10CP-250375mAVOUT=0VOutput voltageVo12.7162.802.884VIo=150mA, VBAT≥3.1VI/O voltage differenceVsat1-0.20.3VVBAT=2.5V, Io=150mALoad stabilityΔV011-1060mVIo=1 to 150mAInput stabilityΔV012-1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR13040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim01-225450mAVo=0VOutput voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stabilityΔV021-1060mVIo=1 to 150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stabilityΔV021-1060mVIo=1 to 150mA (normal mode)Input stabilityΔV021-1060mVIo=1 to 150mA (normal mode)Load stabilityΔV021-<	Output voltage	VoCP	Vf+0.15	Vf+0.2	-	V	Vf is LED forward voltage
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Current Load	IOUT	-	-	255	mA	VBAT≥3.2V, VOUT=4V
detect voltage $0VP$ -6.06.5VOver current protection detect current OCP - 250 375 mA $VOUT=0V$ [REG1]Output voltageVo12.7162.802.884VIo=150mA, VBAT≥3.1VI/O voltage differenceVsat1-0.20.3VVBAT=2.5V, Io=150mALoad stability $\Delta Vo11$ -1060mVIo=1 to 150mAInput stability $\Delta Vo12$ -1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR13040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim01-225450mAVo=0VDischarge resistor at OFFROFF1-1.01.5k Ω Io=150mAOutput voltage 1Vo211.741.81.86VIo=150mAOutput voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stability $\Delta Vo21$ -1060mVIo=100µA (low current consumption mode)Load stability $\Delta Vo21$ -1060mVIo=1 to 150mAInput stability $\Delta Vo22$ -1060mVIo=1 to 150mA (normal mode)Load stability $\Delta Vo22$ -1060mVIo=1 to 150mAInput stability $\Delta Vo22$ -10060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection Ratio <td>Oscillator frequency</td> <td>fosc</td> <td>0.8</td> <td>1.0</td> <td>1.2</td> <td>MHz</td> <td></td>	Oscillator frequency	fosc	0.8	1.0	1.2	MHz	
detect currentOCP-2503/5mAVOU =0V[REG1]Output voltageV012.7162.802.884VIo=150mA, VBAT≥3.1VI/O voltage differenceVsat1-0.20.3VVBAT=2.5V, Io=150mALoad stability Δ Vo11-1060mVIo=1 to 150mAInput stability Δ Vo12-1060mVVBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo12-1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR13040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim01-225450mAVo=0VDischarge resistor at OFFROFF1-1.01.5kΩOutput voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stability Δ Vo21-1060mVVBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo22-1060mVVBAT=3.2 to 5.5V, Io=150mAInput stability Δ Vo22-1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	e 1	OVP	-	6.0	6.5	V	
Output voltage Vo1 2.716 2.80 2.884 V Io=150mA, VBAT≥3.1V I/O voltage difference Vsat1 - 0.2 0.3 V VBAT=2.5V, Io=150mA Load stability Δ Vo11 - 10 60 mV Io=1 to 150mA Input stability Δ Vo12 - 10 60 mV VBAT=3.2 to 5.5V, Io=150mA Ripple Rejection Ratio RR1 30 40 - dB f=100Hz, Vin=200mVp-p Short circuit current limit Ilim01 - 225 450 mA Vo=0V Discharge resistor at OFF ROFF1 - 1.0 1.5 kΩ Qutput voltage 1 Vo21 1.74 1.8 1.86 V Io=150mA (normal mode) Output voltage 2 Vo22 1.71 1.8 1.89 V Io=100µA (low current consumption mode) Load stability Δ Vo21 - 10 60 mV Io=1 to 150mA Input stability Δ Vo22 -	detect current	OCP	-	250	375	mA	VOUT=0V
I/O voltage differenceVsat1-0.20.3VVBAT=2.5V, Io=150mALoad stability $\Delta Vo11$ -1060mVIo=1 to 150mAInput stability $\Delta Vo12$ -1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR13040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim01-225450mAVo=0VDischarge resistor at OFFROFF1-1.01.5kQIo=150mAIREG2Imput voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stability $\Delta Vo21$ -1060mVVBAT=3.2 to 5.5V, Io=150mAInput stability $\Delta Vo22$ -1060mVIo=100µA (low current consumption mode)Load stability $\Delta Vo22$ -1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V		Vo1	2.716	2.80	2.884	V	lo=150mA, VBAT≥3.1V
$\begin{tabular}{ c c c c c c c } \hline ΔVo11 & - & 10 & 60 & mV & $lo=1$ to $150mA$ \\ \hline $lnput$ stability & ΔVo12 & - & 10 & 60 & mV & $VBAT=3.2$ to $5.5V$, $lo=150mA$ \\ \hline $Ripple Rejection Ratio & R1 & 30 & 40 & - & $dB & $f=100Hz$, $Vin=200mVp-p$ \\ \hline $Short$ circuit$ current limit & $llim01 & - & $225 & 450 & mA & $Vo=0V$ \\ \hline $Short$ circuit$ current limit & $llim01 & - & $225 & 450 & mA & $Vo=0V$ \\ \hline $Discharge$ resistor at OFF & $ROFF1 & - & $1.0 & $1.5 & $k\Omega$ \\ \hline $IREG2$ \\ \hline $Utput$ voltage 1 & $Vo21 & $1.74 & $1.8 & $1.86 & V & $lo=150mA$ \\ $(normal$ mode)$ \\ \hline $Output$ voltage 2 & $Vo22 & $1.71 & $1.8 & $1.89 & V & $lo=100\muA$ \\ $(low$ current$ consumption$ mode)$ \\ \hline $Load$ stability & $\Delta Vo21 & - & $10 & $60 & mV & $lo=1$ to $150mA$ \\ $Input$ stability & $\Delta Vo22 & - $ & $10 & $60 & mV & $lo=1$ to $150mA$ \\ $Input$ stability & $\Delta Vo22 & - $ & $10 & $60 & mV & $lo=1$ to $150mA$ \\ $Input$ stability & $\Delta Vo22 & - $ & $10 & $60 & mV & $lo=1$ to $150mA$ \\ $Input$ stability & $RR2 & $30 & $40 & - $ $ $dB $ $f=100Hz$, $Vin=200mVp$-p$ \\ \hline $Short$ circuit$ current limit & $llim02 & - $ & $225 & $450 & $mA $ $Vo=0V$ \\ \hline $Vo=0V$$			-			V	
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	-	ΔVo11	-	10	60	mV	lo=1 to 150mA
Short circuit current limitIlim01-225450mAVo=0VDischarge resistor at OFFROFF1-1.01.5kΩ[REG2]Output voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100µA (low current consumption mode)Load stability Δ Vo21-1060mVIo=1 to 150mA (low current consumption mode)Input stability Δ Vo22-1060mVVBAT=3.2 to 5.5V, Io=150mA (IoHz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	Input stability	ΔVo12	-	10	60	mV	VBAT=3.2 to 5.5V, Io=150mA
Discharge resistor at OFFROFF1-1.01.5kΩIREG2]Output voltage 1Vo211.741.81.86V $Io=150mA$ (normal mode)Output voltage 2Vo221.711.81.89V $Io=100\muA$ (low current consumption mode)Load stability $\Delta Vo21$ -1060mVIo=1 to 150mA (low current consumption mode)Input stability $\Delta Vo22$ -1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	Ripple Rejection Ratio	RR1	30	40	-	dB	f=100Hz, Vin=200mVp-p
Image: Constraint of the	Short circuit current limit	llim01	-	225	450	mA	Vo=0V
Output voltage 1Vo211.741.81.86VIo=150mA (normal mode)Output voltage 2Vo221.711.81.89VIo=100 μ A (low current consumption mode)Load stability Δ Vo21-1060mVIo=1 to 150mA (low current consumption mode)Input stability Δ Vo22-1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	Discharge resistor at OFF	ROFF1	-	1.0	1.5	kΩ	
Output voltage 1Vo211.741.81.86V(normal mode)Output voltage 2Vo221.711.81.89VIo=100μA (low current consumption mode)Load stabilityΔVo21-1060mVIo=1 to 150mAInput stabilityΔVo22-1060mVVBAT=3.2 to 5.5V, Io=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	【REG2】						
Output voltage 2Vo221.711.81.89V(low current consumption mode)Load stabilityΔVo21-1060mVlo=1 to 150mAInput stabilityΔVo22-1060mVVBAT=3.2 to 5.5V, lo=150mARipple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	Output voltage 1	Vo21	1.74	1.8	1.86	V	
Input stability ΔVo22 - 10 60 mV VBAT=3.2 to 5.5V, Io=150mA Ripple Rejection Ratio RR2 30 40 - dB f=100Hz, Vin=200mVp-p Short circuit current limit IIim02 - 225 450 mA Vo=0V	Output voltage 2	Vo22	1.71	1.8	1.89	V	
Ripple Rejection RatioRR23040-dBf=100Hz, Vin=200mVp-pShort circuit current limitIlim02-225450mAVo=0V	Load stability	ΔVo21	-	10	60	mV	lo=1 to 150mA
Short circuit current limit Ilim02 - 225 450 mA Vo=0V	Input stability	ΔVo22	-	10	60	mV	VBAT=3.2 to 5.5V, lo=150mA
	Ripple Rejection Ratio	RR2	30	40	-	dB	f=100Hz, Vin=200mVp-p
Discharge resistor at OFF ROFF2 - 1.0 1.5 kΩ	Short circuit current limit	llim02	-	225	450	mA	Vo=0V
	Discharge resistor at OFF	ROFF2	-	1.0	1.5	kΩ	

Electrical Characteristics - continued (Unless otherwise specified, Ta=25 , VBAT=3.6V, VIO=1.8V)

Parameter	Symbol		Limits		Unit	Condition	
Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition	
【I ² C Input (SDA, SCL)】							
LOW level input voltage	VIL	-0.3	-	0.25 ×VIO	V		
HIGH level input voltage	VIH	0.75 ×VIO	-	VBAT+0.3	V		
Hysteresis of Schmitt trigger input	Vhys	0.05 ×VIO	-	-	V		
LOW level output voltage (SDA) at 3mA sink current	VOL	0	-	0.3	V		
Input current each I/O pin	lin	-10	-	10	μΑ	Input voltage = 0.1×VIO to 0.9×VIO	
[RESET, RGB1CNT, RGB2CNT]					-	
LOW level input voltage	VIL	-0.3	-	0.25 ×VIO	V		
HIGH level input voltage1	VIH1	0.75 ×VIO	-	VBAT+0.3	V	RESET Pin	
HIGH level input voltage2	VIH2	0.75 ×VIO	-	VIO+0.3	V	RGB1CNT, RGB2CNT Pin	
Input current each I/O pin1	lin	-10	-	10	μA	Input voltage = 0.1×VIO to 0.9×VIO,RESET Pin	
Input current each I/O pin2	lin	-	6	15	μΑ	Input voltage = 0.9×VIO RGB1CNT, RGB2CNT Pin	
【REG2EN, REG2MD】							
LOW level input voltage	VIL	-0.3	-	0.3	V		
HIGH level input voltage	VIH	1.4	-	VBAT+0.3	V		
Input current each I/O pin	lin	-	6	15	μA	Vin=1.8V	

(Unless otherwise specified, Ta=25 , VBAT=3.6V, VIO=1.8V)

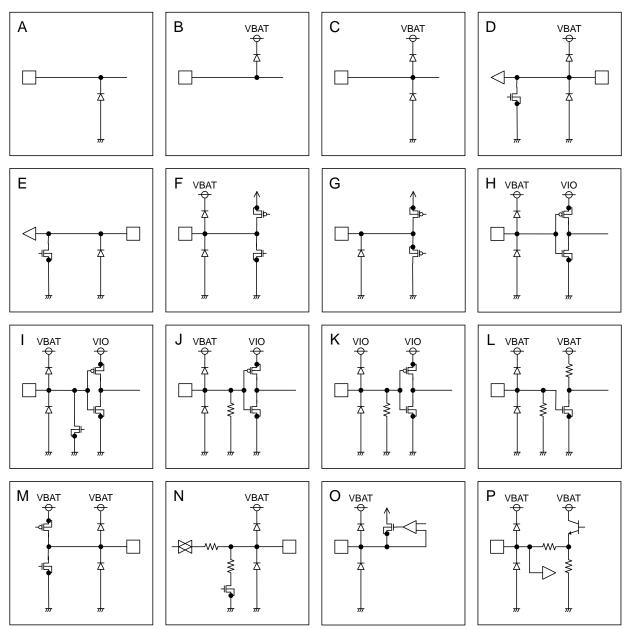
	C: mah al	Sta	ndard-m	ode	Fast-mode			Linit			
Parameter	Symbol	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit			
[I ² C BUS format]	[I ² C BUS format]										
SCL clock frequency	fscl	0	-	100	0	-	400	kHz			
LOW period of the SCL clock	tLOW	4.7	-	-	1.3	-	-	μs			
HIGH period of the SCL clock	thigh	4.0	-	-	0.6	-	-	μs			
Hold time (repeated) START condition After this period, the first clock is generated	thd;sta	4.0	-	-	0.6	-	-	μs			
Set-up time for a repeated START condition	tSU;STA	4.7	-	-	0.6	-	-	μs			
Data hold time	thd;dat	0	-	3.45	0	-	0.9	μs			
Data set-up time	tsu;dat	250	-	-	100	-	-	ns			
Set-up time for STOP condition	tsu;sto	4.0	-	-	0.6	-	-	μs			
Bus free time between a STOP and START condition	tBUF	4.7	-	-	1.3	-	-	μs			

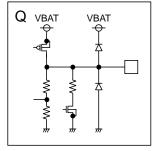
Pin Descriptions

	Pir	n No.				ESD	Diode		
No	BD6081GU	BD6081GVW	Pin Name	I/O	Input Level	For Power	For Ground	Functions	Equivalent circuit diagra
1	B7	E4	VBATCP	-	-	-	GND	Battery is connected	А
2	G2	B8	VBAT1	-	-	-	GND	Battery is connected	A
3	A5	E3	VBAT2	-	-	-	GND	Battery is connected	A
4	G4	D7	VBATREG	-	-	-	GND	Battery is connected	A
5	A1	A1	T1	-	-	-	GND	Test Pin (short to GND)	A
6	A7	H1	T2	-	-	-	GND	Test Pin (short to GND)	А
7	G7	H8	Т3	-	-	VBAT	GND	Test Pin (short to GND)	J
8	G1	A8	T4	-	-	VBAT	GND	Test Pin (short to GND)	J
9	F3	C7	CREF	0	-	VBAT	GND	Reference voltage output	P
10	G6	G8	VIO	-	-	VBAT	GND	I/O voltage source is connected	C
11	F7	H7	RESET	1	VIO	VBAT	GND	Reset input (L: RESET, H: RESET cancel)	н
12	E6	H6	SDA		VIO	VBAT	GND	I^2C data input	1
13	D5	G6	SCL		VIO	VBAT	GND	I ² C clock input	н
13	B5	60 F1	CPGND	-	-	VBAT	- GIND	Ground	В
14	F1	B6	REFGND	-	-	VBAT	-	Ground	В
	G5	E7		-	-	VBAT			В
16			REGGND	-			-	Ground	
17	B2	C2	BLGND	-	-	VBAT	-	Ground	В
18	D1	A3	RGBGND	-	-	VBAT	-	Ground	В
19	E7	F5	DGND	-	-	VBAT	-	Ground	В
20	B6	G1	C1N	I/O	-	VBAT	GND	Charge Pump capacitor is connected	F
21	C6	H2	C1P	I/O	-	-	GND	Charge Pump capacitor is connected	G
22	A6	F2	C2N	I/O	-	VBAT	GND	Charge Pump capacitor is connected	F
23	C7	H3	C2P	I/O	-	-	GND	Charge Pump capacitor is connected	G
24	D7	F4	VOUT	0	-	-	GND	Charge Pump output pin	A
25	D6	G4	VOUTM	0	-	-	GND	Charge Pump output pin output pin	A
26	E3	A7	ISET	I	-	VBAT	GND	LED standard current	0
27	F4	D6	REG10	0	-	VBAT	GND	REG1 output pin	Q
28	G3	C8	REG2O	0	-	VBAT	GND	REG2 output pin	Q
29	A3	D3	MLED1	I	-	VBAT	GND	Main LCD Back Light LED is connected 1	D
30	B3	D1	MLED2	1	-	VBAT	GND	Main LCD Back Light LED is connected 2	D
31	A4	E1	MLED3	I	-	VBAT	GND	Main LCD Back Light LED is connected 3	D
32	B4	E2	MLED4	I.	-	VBAT	GND	Main LCD Back Light LED is connected 4	D
33	B1	B2	SLED1	I.	-	VBAT	GND	Sub LCD Back Light LED is connected 1	D
34	A2	B1	SLED2	I	-	VBAT	GND	Sub LCD Back Light LED is connected 2	D
35	F2	A6	R1LED	I	-	VBAT	GND	Red LED1 is connected	D
36	E1	A5	G1LED	I	-	VBAT	GND	Green LED1 is connected	D
37	E2	A4	B1LED	I	-	VBAT	GND	Blue LED1 is connected	D
38	D2	B3	R2LED	I	-	VBAT	GND	Red LED2 is connected	D
39	C1	A2	G2LED	I	-	VBAT	GND	Green LED2 is connected	D
40	C2	C3	B2LED	I	-	VBAT	GND	Blue LED2 is connected	D
41	F6	F6	RGB1CNT	I	VIO	VIO	GND	RGB1 LED external ON/OFF Synchronism Pin	К
42	E5	G7	RGB2CNT	I	VIO	VIO	GND	RGB2 LED external ON/OFF Synchronism Pin	К
43	E4	E6	REG2EN		(VBAT)	VBAT	GND	REG2 ON/OFF control Pin (L: OFF, H: ON)	L
44	F5	F8	REG2MD	I	(VBAT)	VBAT	GND	REG2 Mode control Pin (L: low current consumption, H: normal)	L
45	D3	F3	TESTI1	1	-	VBAT	GND	Test input pin 1 (short to GND)	Н
46	D3	C6	TESTI2	1	-	VBAT	GND	Test input pin 2 (short to GND)	Н
40	C5	G5	TESTO1	0	-	VBAT	GND	Test output pin 1 (OPEN)	M
48	C4	F7	TESTO2	0	-	VBAT	GND	Test output pin 2 (OPEN)	N
49 - 63	-	(Other)	NC	-	-	-	-	Non connect pin	-

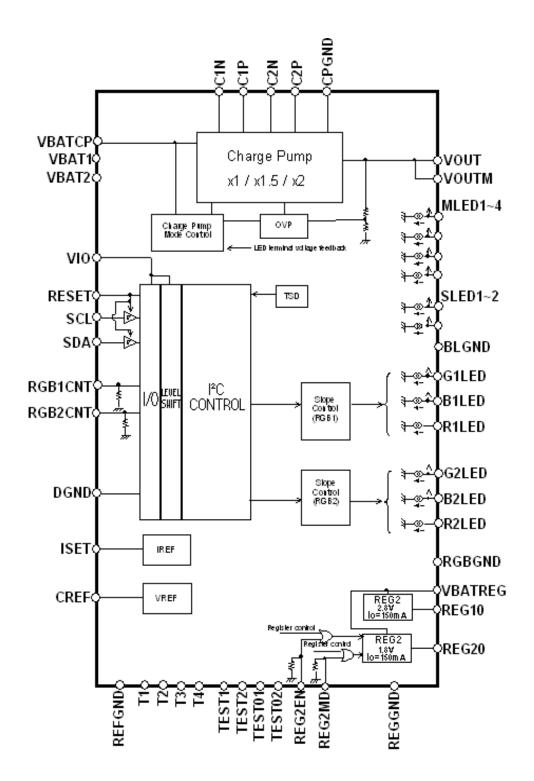
The LED pin which isn't used is to short-circuit to the ground. But, the setup of a register concerned with LED that isn't used is prohibited. Total: Functional 48Pin 48 balls (BD6081GU) 63 balls (BD6081GVW)

Pin ESD Type





Block Diagram



I²C BUS Format

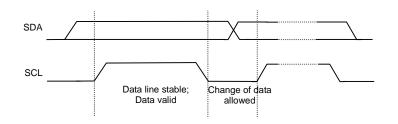
The writing/reading operation is based on the I^2C slave standard.

Slave address

A7	A6	A5	A4	A3	A2	A1	W
1	1	1	0	1	1	0	0

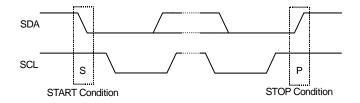
Bit Transfer

SCL transfers 1-bit data during H. SCL cannot change signal of SDA during H at the time of bit transfer. If SDA changes while SCL is H, START conditions or STOP conditions will occur and it will be interpreted as a control signal.



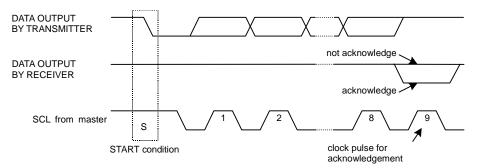
START and STOP condition

When SDA and SCL are H, data is not transferred on the I^2 C- bus. This condition indicates, if SDA changes from H to L while SCL has been H, it will become START (S) conditions, and an access start, if SDA changes from L to H while SCL has been H, it will become STOP (P) conditions and an access end.



Acknowledge

It transfers data 8 bits each after the occurrence of START condition. A transmitter opens SDA after transfer 8bits data, and a receiver returns the acknowledge signal by setting SDA to L.



-HD:STA

S

t HD;DA

I THIGH

Writing protocol

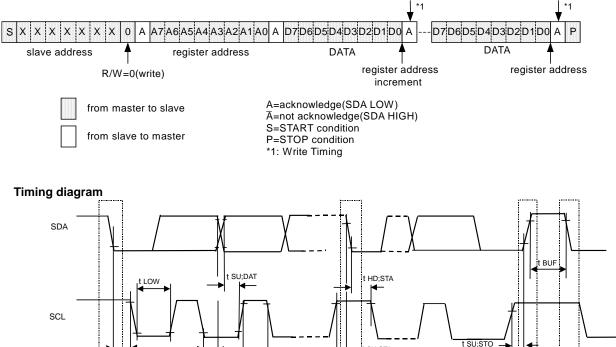
A register address is transferred by the next 1 byte that transferred the slave address and the write-in command. The 3rd byte writes data in the internal register written in by the 2nd byte, and after 4th byte or, the increment of register address is carried out automatically. However, when a register address turns into the last address (1Ah), it is set to 00h by the next transmission. After the transmission end, the increment of the address is carried out.

SU:STA

Ρ

S

Sr



Register List

Address				Regis	ter data				Function	
Address	D7	D6	D5	D4	D3	D2	D1	D0	Function	
00h	-	-	-	-	-	-	-	SFTRST	Software reset	
01h	-	-	REG2NML	REG2PD	-	-	-	REG1PD	Control LDO	
02h	-	-	SLEDSEL	SLEDEN	-	-	MLEDSEL	MLEDEN	Control Back Light	
03h	-	-	-	IMLED4	IMLED3	IMLED2	IMLED1	IMLED0	Main Back Light current value	
04h	-	-	-	ISLED4	ISLED3	ISLED2	ISLED1	ISLED0	Sub Back Light current value	
05h	-	B2LEDMD	G2LEDMD	RGB2STA	-	B1LEDMD	G1LEDMD	RGB1STA	Control RGB1, RGB2 LED Setting GB LED connection	
06h	RGB1MD1	RGB1MD0	B1LEDPL	G1LEDPL	R1LEDPL	B1LEDEN	G1LEDEN	R1LEDEN	Control RGB1 LED	
07h	RGB1WT1TM3	RGB1WT1TM2	RGB1WT1TM1	RGB1WT1TM0	RGB1WT2TM3	RGB1WT2TM2	RGB1WT2TM1	RGB1WT2TM0	RGB1 ON time setting	
08h	RGB1SL1 STEP3	RGB1SL1 STEP2	RGB1SL1 STEP1	RGB1SL1 STEP0	RGB1SL2 STEP3	RGB1SL2 STEP2	RGB1SL2 STEP1	RGB1SL2 STEP0	RGB1 slope 1step time setting	
09h	-	-	-	-	-	RGB1SLNUM2	RGB1SLNUM1	RGB1SLNUM0	RGB1 slope step number settir	
0Ah	-	-	I1R1LED5	I1R1LED4	I1R1LED3	I1R1LED2	I1R1LED1	I1R1LED0	R1 LED current value1	
0Bh	-	-	IDLTR1LED5	IDLTR1LED4	IDLTR1LED3	IDLTR1LED2	IDLTR1LED1	IDLTR1LED0	∆ current value for R1 LED current step	
0Ch	-	-	I1G1LED5	I1G1LED4	I1G1LED3	I1G1LED2	I1G1LED1	I1G1LED0	G1 LED current value1	
0Dh	-	-	IDLTG1LED5	IDLTG1LED4	IDLTG1LED3	IDLTG1LED2	IDLTG1LED1	IDLTG1LED0	Δ current value for G1 LED current step	
0Eh	-	-	I1B1LED5	I1B1LED4	I1B1LED3	I1B1LED2	I1B1LED1	I1B1LED0	B1 LED current value1	
0Fh	-	-	IDLTB1LED5	IDLTB1LED4	IDLTB1LED3	IDLTB1LED2	IDLTB1LED1	IDLTB1LED0	Δ current value for B1 LED current step	
10h	RGB2MD1	RGB2MD0	B2LEDPL	G2LEDPL	R2LEDPL	B2LEDEN	G2LEDEN	R2LEDEN	Control RGB2 LED	
11h	RGB2WT1TM3	RGB2WT1TM2	RGB2WT1TM1	RGB2WT1TM0	RGB2WT2TM3	RGB2WT2TM2	RGB2WT2TM1	RGB2WT2TM0	RGB2 ON time setting	
12h	RGB2SL1 STEP3	RGB2SL1 STEP2	RGB2SL1 STEP1	RGB2SL1 STEP0	RGB2SL2 STEP3	RGB2SL2 STEP2	RGB2SL2 STEP1	RGB2SL2 STEP0	RGB2 slope 1step time setting	
13h	-	-	-	-	-	RGB2SLNUM2	RGB2SLNUM1	RGB2SLNUM0	RGB2 slope step number setti	
14h	-	-	I1R2LED5	I1R2LED4	I1R2LED3	I1R2LED2	I1R2LED1	I1R2LED0	R2 LED current value1	
15h	-	-	IDLTR2LED5	IDLTR2LED4	IDLTR2LED3	IDLTR2LED2	IDLTR2LED1	IDLTR2LED0	Δ current value for R2 LED current step	
16h	-	-	I1G2LED5	I1G2LED4	I1G2LED3	I1G2LED2	I1G2LED1	I1G2LED0	G2 LED current value1	
17h	-	-	IDLTG2LED5	IDLTG2LED4	IDLTG2LED3	IDLTG2LED2	IDLTG2LED1	IDLTG2LED0	Δ current value for G2 LED current step	
18h	-	-	I1B2LED5	I1B2LED4	I1B2LED3	I1B2LED2	I1B2LED1	I1B2LED0	B2 LED current value1	
19h	-	-	IDLTB2LED5	IDLTB2LED4	IDLTB2LED3	IDLTB2LED2	IDLTB2LED1	IDLTB2LED0	Δ current value for B2 LED current step	
1Ah	-	-	-	-	-	-	RGB2MEL	RGB1MEL	RGB1, RGB2 LED external ON/OFF control	
1Dh		For test								
1Eh		For test								
1Fh	Reserved For test									

Input "0" for "-". Prohibit to accessing the address that isn't mentioned and the register for test.

Register Map

Address 00h <Software reset>

ыт	Nomo	Initial	Fund	ction
BIT	Name	mua	0	1
D7	-	-	-	-
D6	-	-	-	-
D5	-	-	-	-
D4	-	-	-	-
D3	-	-	-	-
D2	-	-	-	-
D1	-	-	-	-
D0	SFTRST	0	Reset cancel	Reset

Address 01h <Control LDO>

ыт	Nomo	Initial	Function				
BIT	Name	Initial	0	1			
D7	-	-	-	-			
D6	-	-	-	-			
D5	REG2NML	0	REG2 low current consumption mode	REG2 normal mode			
D4	REG2PD	0	REG2 power OFF	REG2 power ON			
D3	-	-	-	-			
D2	-	-	-	-			
D1	-	-	-	-			
D0	REG1PD	0	REG1 power OFF	REG1 power ON			

Address 02h <Control Back Light>

BIT	Nome	Initial	Func	tion
ыі	Name	mua	0	1
D7	-	-	-	-
D6	-	-	-	-
D5	SLEDSEL	0	2 lights ON (SLED1 to 2)	1 lights ON (SLED1)
D4	SLEDEN	0	Sub Back Light OFF	Sub Back Light ON
D3	-	-	-	-
D2	-	-	-	-
D1	MLEDSEL	0	4 lights ON (MLED1 to 4)	3 lights ON (MLED1 to 3)
D0	MLEDEN	0	Main Back Light OFF	Main Back Light ON

Address 03h <Main Back Light current value>

BIT	Name	Initial				Function				
DII	Iname	Initial		0				1		
D7	-	-		-			-			
D6	-	-		-				-		
D5	-	-		-				-		
D4	IMLED4	0								
D3	IMLED3	0	IMLED4	IMLED3	IMLED2	IMLED1	IMLED0	Current value		
D2	IMLED2	0	0	0	0	0	0	1mA		
D1	IMLED1	0	0	0	0	0	1	2mA		
D0	IMLED0	0	0	0	0	1	0	3mA		
			•	•	•	•	•	4		
			•	•	•	•	•	1mA		
			•	•	•	•	•	Step		
			1	1	1	0	1	30mA		
			1	1	1	1	0	31mA		
			1	1	1	1	1	32mA		
			When 120	kΩ is conn	ected to IS	ET pin.				

Address 04h <Sub Back Light current value>

BIT	Name	Initial				Function				
ып	Name	initial		0				1		
D7	-	-		-			-			
D6	-	-		-				-		
D5	-	-		-				-		
D4	ISLED4	0		P	1	P	P			
D3	ISLED3	0	ISLED4	ISLED3	ISLED2	ISLED1	ISLED0	Current value		
D2	ISLED2	0	0	0	0	0	0	1mA		
D1	ISLED1	0	0	0	0	0	1	2mA		
D0	ISLED0	0	0	0	0	1	0	3mA		
			•	•	•	•	•	4 0		
			•	•	•	•	•	1mA		
			•	•	•	•	•	Step		
			1	1	1	0	1	30mA		
			1	1	1	1	0	31mA		
			1 1 1				1	32mA		
			When 120	kΩ is conn	ected to IS	SET pin.				

Address 05h <Control RGB1, RGB2 LED, Setting GB LED connection>

BIT	Name	Initial	Func	tion
ыі	Name	mua	0	1
D7	-	-	-	-
D6	B2LEDMD	0	B2LED connection =VBAT	B2LED connection =VOUT
D5	G2LEDMD	0	G2LED connection =VBAT	G2LED connection =VOUT
D4	RGB2STA	0	RGB2 LED Lighting stop	RGB2 LED Lighting start
D3	-	-	-	-
D2	B1LEDMD	0	B1LED connection =VBAT	B1LED connection =VOUT
D1	G1LEDMD	0	G1LED connection =VBAT	G1LED connection =VOUT
D0	RGB1STA	0	RGB1 LED Lighting stop	RGB1 LED Lighting start

Address 06h <Control RGB1 LED>

віт	Name	Initial	Function								
DII	Inallie	Initial		0		1					
D7	RGB1MD1	0	Refer to	the following		Refer to the following					
D6	RGB1MD0	0	Refer to	the following			Refer to the following				
D5	B1LEDPL	0	Refer to	the following			Refer to the following				
D4	G1LEDPL	0	Refer to	the following			Refer to the following				
D3	R1LEDPL	0	Refer to	the following			Refer to the following				
D2	B1LEDEN	0	B1 L	ED OFF			B1 LED ON				
D1	G1LEDEN	0	G1 L	ED OFF		G1 LED ON					
D0	R1LEDEN	0	R1 L	ED OFF			R1 LED ON				
			_								
			RGB1MD1	RGB1MD0	*1LE	DPL	Mode				
			0	0	0	/ 1	Normal 1				
			0	1	0	/ 1	Normal 2				
			1	0	()	Blink 1				
			I	0		1	Blink 2				
			1	4	(C	Slope 1				
				1	1	Slope 2					
			*1LEDPL : R1	LEDPL, G1LED	PL, B1	LEDPL	is shown.				

Address 07h <RGB1 ON time setting>

			0							
BIT	Name	Initial			Functio	n				
D7	RGB1WT1TM3	0								
D6	RGB1WT1TM2	0	RGB1WT1TM	3 RGB1WT1TM	2 RGB1WT1TM	1 RGB1WT1TM0	Current light time			
D5	RGB1WT1TM1	0	0	0	0	0	0.256s			
D4	RGB1WT1TM0	0	0	0	0	1	0.512s			
			•	•	•	· · ·	0.256s Step			
			1	1	0	1	3.584s			
			1	1	1	0	3.84s			
			1	1	1	1	4.096s			
D3	RGB1WT2TM3	0			internal OSC fi	equency.				
D2	RGB1WT2TM2	0	RGB1WT2TM3	RGB1WT2TM2	RGB1WT2TM1	RGB1WT2TM0	Current light time			
D1	RGB1WT2TM1	0	0	0	0	0	0.256s			
D0	RGB1WT2TM0	0	0	0	0	1	0.512s			
			•	•	•	•	0.256s Step			
			1	1	0	1	3.584s			
			1	1	1	0	3.84s			
			1 1 1 1 4.096s							
			Lighting time	e depends on	internal OSC fi	equency				

Lighting time depends on internal OSC frequency.

Address 08h <RGB1 slope 1step time setting>

BIT	Name	Initial	Function									
D7	RGB1SL1STEP3	0										
D6	RGB1SL1STEP2	0	RGB1SL1 STEP3	RGB1SL1 STEP2	RGB1SL1 STEP1	RGB1SL1 STEP0	Current light time					
D5	RGB1SL1STEP1	0	0	0	0	0	4ms					
D4	RGB1SL1STEP0	0	0	0	0	1	8ms					
			•	•	•	•	4ms Step					
			1	1	0	1	56ms					
			1	1	1	0	60ms					
			1	1	1	1	64ms					
D3 D2	RGB1SL2STEP3 RGB1SL2STEP2	0	RGB1SL2 STEP3	RGB1SL2 STEP2	RGB1SL2 STEP1	RGB1SL2 STEP0	Current light time					
D1	RGB1SL2STEP1	0	0	0	0	0	4ms					
D0	RGB1SL2STEP0	0	0	0	0	1	8ms					
			•	•	•	•	4ms Step					
			1	1	0	1	56ms					
			1	1	1	0	60ms					
			1	1	1	1	64ms					
Lighting time depends on internal OSC frequency.												

Address 09h <RGB1 slope step number setting>

BIT	Name	Initial		Fu	Inction			
DII	Name	mua	0		1			
D7	-	-	-		-			
D6	-	-	-			-		
D5	-	-	-			-		
D4	-	-	-			-		
D3	-	-						
D2	RGB1SLNUM2	0		1	1			
D1	RGB1SLNUM1	0	RGB1SLNUM2	RGB1SLNUM1	RGB1SLNUM0	Step		
D0	RGB1SLNUM0	0	0	0	0	1 Step		
			0	0	1	2 Step		
			0	1	0	4 Step		
			0	1	1	8 Step		
			1	0	0	16 Step		
			1	0	1	32 Step		
			1	1	0	64 Step		
			1	1	1	(Prohibited)		

Address 0Ah <R1 LED current value 1>

BIT	Name	Initial		Function								
ы	Name	Initial	0							1		
D7	-	-			-					-		
D6	-	-			-					-		
D5	I1R1LED5	0	_									
D4	I1R1LED4	0		l1R1 LED5	I1R1 LED4	I1R1 LED3	I1R1 LED		I1R1 LED1	I1R1 LED0	Current value	
D3	I1R1LED3	0		0	0	0	0		0	0	0mA	
D2	I1R1LED2	0		0	0	0	0		0	1	0.5mA	
D1	I1R1LED1	0		0	0	0	0		1	0	1mA	
D0	I1R1LED0	0		•	•	•	•		•	•		
				•	•	•	•		•	•	0.5mA	
				•	٠	•	•		•	•	Step	
				•	•	•	•		•	•		
				1	1	1	1		0	1	30.5mA	
				1	1	1	1		1	0	31mA	
				1	1	1	1		1	1	31.5mA	
When 120kΩ is connected to ISET pin.												

Address 0Bh <Δ current value for R1 LED current step>

BIT	Name	Initial					Fu	Inctio	า			
DII	Name	milla			0					1		
D7	-	-			-			-				
D6	-	-			-					-		
D5	IDLTR1LED5	0	_									
D4	IDLTR1LED4	0		IDLTR1	IDLTR1	IDLTR1	IDL	TR1	IDLTR1	IDLTR1	Current value	
04	IDEI KILED4	0		LED5	LED4	LED3	LE	D2	LED1	LED0	Current value	
D3	IDLTR1LED3	0		0	0	0	()	0	0	0mA	
D2	IDLTR1LED2	0		0	0	0	0)	0	1	0.5mA	
D1	IDLTR1LED1	0		0	0	0	()	1	0	1mA	
D0	IDLTR1LED0	0		•	•	•		•	•	•		
				•	•	•		•	•	•	0.5mA	
				•	•	•		•	•	٠	Step	
				•	•	•		•	•	•		
				1	1	1	1	1	0	1	30.5mA	
				1	1	1	1	1	1	0	31mA	
				1	1	1	1		1	1	31.5mA	
	When 120kΩ is connected to ISET pin.											

Address 0Ch <G1 LED current value1>

BIT	Name	Initial				Fu	nctio	n		
ы	Name	miliai		0					1	
D7	-	-		-					-	
D6	-	-		-					-	
D5	I1G1LED5	0								
D4	I1G1LED4	0	I1G ⁻		I1G1	110		I1G1	I1G1	Current
	HOILEDA	U	LED	5 LED4	LED3	LE	D2	LED1	LED0	value
D3	I1G1LED3	0	0	0	0	()	0	0	0mA
D2	I1G1LED2	0	0	0	0	()	0	1	0.5mA
D1	I1G1LED1	0	0	0	0	()	1	0	1mA
D0	I1G1LED0	0	•	•	•		•	•	•	
			•	•	•		•	•	•	0.5mA
			•	•	•		•	•	•	Step
			•	•	•		•	•	•	
			1	1	1	1	1	0	1	30.5mA
			1	1	1	1		1	0	31mA
			1	1	1	1	I	1	1	31.5mA
			Whe	n 120kΩ is c	onnected to	ISET	pin.			

Address 0Dh <Δ current value for G1 LED current step >

BIT	Name	Initial					Fu	Inctio	า		
DII	Name	miliai			0					1	
D7	-	-	-							-	
D6	-	-			-					-	
D5	IDLTG1LED5	0									
D4	IDLTG1LED4	0	IDI	_TG1	IDLTG1	IDLTG1	IDL	TG1	IDLTG1	IDLTG1	Current value
	IDLI GILED4	0	LI	ED5	LED4	LED3	LE	D2	LED1	LED0	Current value
D3	IDLTG1LED3	0		0	0	0	()	0	0	0mA
D2	IDLTG1LED2	0		0	0	0	()	0	1	0.5mA
D1	IDLTG1LED1	0		0	0	0	()	1	0	1mA
D0	IDLTG1LED0	0		•	•	•		•	•	•	
				•	•	•		•	•	•	0 5 4 01
				•	•	•		•	•	•	0.5mAStep
				•	•	•		•	•	•	
				1	1	1	1	1	0	1	30.5mA
				1	1	1	1	1	1	0	31mA
				1	1	1	1	1	1	1	31.5mA
			W	hen 12	20kΩ is cor	nnected to	ISET	pin.			

Address 0Eh <B1 LED Current value1>

BIT	Name	Initial		Function							
ы	Name	Initial			0					1	
D7	-	-	-							-	
D6	-	-			-					-	
D5	I1B1LED5	0	_			1				n	
D4	I1B1LED4	0		I1B1 LED5	I1B1 LED4	I1B1 LED3	I1E LE	31 D2	I1B1 LED1	I1B1 LED0	Current value
D3	I1B1LED3	0		0	0	0	0)	0	0	0mA
D2	I1B1LED2	0		0	0	0	()	0	1	0.5mA
D1	I1B1LED1	0		0	0	0	0)	1	0	1mA
D0	I1B1LED0	0		•	•	•		•	•	•	
				•	•	•	•	•	•	•	0.5mA
				•	•	•		•	•	•	Step
				•	•	•		•	•	•	
				1	1	1	1	1	0	1	30.5mA
				1	1	1	1	1	1	0	31mA
				1	1	1	1	1	1	1	31.5mA
				When 12	20kΩ is cor	nnected to	ISET	pin.			

Address 0Fh $<\Delta$ current value for B1 LED current step >

BIT	Name	Initial	Function									
ЫТ	Iname	milla		0				1				
D7	-	-		-				-				
D6	-	-		-				-	-			
D5	IDLTB1LED5	0										
D4	IDLTB1LED4	0	IDLTB1 LED5	IDLTB1 LED4	IDLTB1 LED3	IDLTB1 LED2	IDLTB1 LED1	IDLTB1 LED0	Current value			
D3	IDLTB1LED3	0	0	0	0	0	0	0	0mA			
D2	IDLTB1LED2	0	0	0	0	0	0	1	0.5mA			
D1	IDLTB1LED1	0	0	0	0	0	1	0	1mA			
D0	IDLTB1LED0	0	•	•	•	•	•	•				
			•	•	•	•	•	•	0.5mA			
			•	•	•	•	•	•	Step			
			•	•	•	•	•	•				
			1	1	1	1	0	1	30.5mA			
			1	1	1	1	1	0	31mA			
			1	1	1	1	1	1	31.5mA			

Address	10h <control r<="" th=""><th>GB2 LED></th><th></th><th></th><th></th><th></th><th></th><th></th></control>	GB2 LED>								
BIT	Name	Initial			Fur	nction				
DII	Name	minai		0			1			
D7	RGB2MD1	0	Refer to	o following			Refer to following			
D6	RGB2MD0	0	Refer to	o following			Refer to following			
D5	B2LEDPL	0	Refer to	o following			Refer to following			
D4	G2LEDPL	0	Refer to	o following			Refer to following			
D3	R2LEDPL	0	Refer to	o following			Refer to following			
D2	B2LEDEN	0	B2 LI	ED OFF			B2 LED ON			
D1	G2LEDEN	0	G2 L	ED OFF			G2 LED ON			
D0	R2LEDEN	0	R2 L	ED OFF			R2 LED ON			
			RGB2MD1	RGB2MD0	*2L	EDPL	Mode			
			0	0	0	/1	Normal 1			
			0	1	0	/1	Normal 2			
			4	0		0	Blink 1			
			I	0		1	Blink 2			
			4	4		0	Slope 1			
						1	Slope 2			
			*2LEDP	L : R2LEDPL, G	2LED	PL, B2L	EDPL is shown.			
L										

Address 11h <RGB2 ON time setting>

BIT	Name	Initial			Function	on	
D7	RGB2WT1TM3	0					
D6	RGB2WT1TM2	0	RGB2WT1	RGB2WT1	RGB2WT1	RGB2WT1	Current ON time
00	RGDZWTTTWZ	0	TM3	TM2	TM1	TM0	setting
D5	RGB2WT1TM1	0	0	0	0	0	0.256s
D4	RGB2WT1TM0	0	0	0	0	1	0.512s
			•	•	•	•	0.256s
			•	•	•	•	Step
			•	•	•	•	ыер
			1	1	0	1	3.584s
			1	1	1	0	3.845s
			1	1	1	1	4.096s
D3	RGB2WT2TM3	0				nternal OSC fr	oquonoj.
Do	DODOW/TOTMO	0	RGB2WT2	RGB2WT2	RGB2WT2	RGB2WT2	Current ON time
D2	RGB2WT2TM2	0	TM3	TM2	TM1	TM0	setting
D1	RGB2WT2TM1	0	0	0	0	0	0.256s
D0	RGB2WT2TM0	0	0	0	0	1	0.512s
			•	•	•	•	0.256s Step
			1	1	0	1	3.584s
			1	1	1	0	3.845s
			1	1	1	1	4.096s
				Lighting time	depends on i	nternal OSC fr	equency.

Address 12h <RGB2 slope 1step time setting>

BIT	Name	Initial			Functi	on	
D7	RGB2SL1STEP3	0	_				
D6	RGB2SL1STEP2	0	RGB2SL1STEP3	RGB2SL1STEP2	RGB2SL1STEP1	RGB2SL1STEP0	Current ON time setting
D5	RGB2SL1STEP1	0	0	0	0	0	4ms
D4	RGB2SL1STEP0	0	0	0	0	1	8ms
			•	•	•	•	4.00.0
			•	•	•	•	4ms Step
			•	•	•	•	Step
			1	1	0	1	56ms
			1	1	1	0	60ms
			1	1	1	1	64ms
		0					
D3	RGB2SL2STEP3	0					Ourset ON View of the
D2	RGB2SL2STEP2	0	RGB2SL2STEP3	RGB2SL2STEP2			Current ON time setting
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0	0	0	0	4ms
D2	RGB2SL2STEP2	0					0
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0	0	0	0	4ms 8ms
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0	0	0	0	4ms 8ms 4ms
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0	0	0	0	4ms 8ms
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0	0	0	0	4ms 8ms 4ms
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0 0	0	0 0	0 1	4ms 8ms 4ms Step
D2 D1	RGB2SL2STEP2 RGB2SL2STEP1	0	0 0 1	0 0 1	0 0 0	0 1 1	4ms 8ms 4ms Step 56ms

Address 13h <RGB2 slope step number setting>

BIT	Name	Initial		Fu	Inction			
ыт	Name	Initial	0		1			
D7	-	-	-			-		
D6	-	-	-			-		
D5	-	-	-			-		
D4	-	-	-			-		
D3	-	-						
D2	RGB2SLNUM2	0						
D1	RGB2SLNUM1	0	RGB2SLNUM2	RGB2SLNUM1	RGB2SLNUM0	Step		
D0	RGB2SLNUM0	0	0	0	0	1 Step		
			0	0	1	2 Step		
			0	1	0	4 Step		
			0	1	1	8 Step		
			1	0	0	16 Step		
			1	0	1	32 Step		
			1	1	0	64 Step		
			1	1	1	(Prohibited)		

Address 14h <R2 LED current value1>

BIT	Name	Initial	Function									
ыт	Inallie	miliai		0				1				
D7	-	-		-				-				
D6	-	-		-				-				
D5	I1R2LED5	0										
D4	I1R2LED4	0	I1R2LED5	I1R2LED4	I1R2LED3	I1R2LED2	I1R2LED1	I1R2LED0	Current value			
D3	I1R2LED3	0	0	0	0	0	0	0	0mA			
D2	I1R2LED2	0	0	0	0	0	0	1	0.5mA			
D1	I1R2LED1	0	0	0	0	0	1	0	1mA			
D0	I1R2LED0	0	•	•	•	•	•	•				
			•	•	•	•	•	•	0.5mA			
			•	•	•	•	•	•	Step			
			•	•	•	•	•	•				
			1	1	1	1	0	1	30.5mA			
			1	1	1	1	1	0	31mA			
			1	1	1	1	1	1	31.5mA			
When $120k\Omega$ is connected to ISET pin.												

Address 15h < \Delta current value for R2 LED current step >

BIT	Name	Initial	Function 0 1								
DII	Name	milla					1				
D7	-	-		-					-		
D6	-	-		-				-			
D5	IDLTR2LED5	0									
D4	IDLTR2LED4	0	IDLTR2	IDLTR2	IDLTR2	IDLT	R2	IDLTR2	IDLTR2	Current	
04		0	LED5	LED4	LED3	LED	02	LED1	LED0	value	
D3	IDLTR2LED3	0	0	0	0	0		0	0	0mA	
D2	IDLTR2LED2	0	0	0	0	0		0	1	0.5mA	
D1	IDLTR2LED1	0	0	0	0	0		1	0	1mA	
D0	IDLTR2LED0	0	•	•	•	•		•	•		
			•	•	•	•		•	•	0.5mA	
			•	•	•	•		•	•	Step	
			•	•	•	•		•	•		
			1	1	1	1		0	1	30.5mA	
			1	1	1	1		1	0	31mA	
			1	1	1	1		1	1	31.5mA	
			When 1	20kΩ is cor	nnected to	ISET p	oin.				

BIT	Name	Initial				Funct	ion					
ЫТ	Name	miliai		0				1				
D7	-	-		-				-				
D6	-	-		-				-				
D5	I1G2LED5	0										
D4	I1G2LED4	0	I1G2LEI	D I1G2LED	I1G2LED	I1G2LED	I1G2LED	I1G2LED	Current value			
04	1162LLD4	0	5	4	3	2	1	0	Current value			
D3	I1G2LED3	0	0	0	0	0	0	0	0mA			
D2	I1G2LED2	0	0	0	0	0	0	1	0.5mA			
D1	I1G2LED1	0	0	0	0	0	1	0	1mA			
D0	I1G2LED0	0	•	•	•	•	•	•				
			•	•	•	•	•	•	0.5mA			
			•	•	•	•	•	•	Step			
			•	•	•	•	•	•				
			1	1	1	1	0	1	30.5mA			
			1	1	1	1	1	0	31mA			
			1	1	1	1	1	1	31.5mA			
			When $120k\Omega$ is connected to ISET pin.									

Address 16h <G2 LED current value1>

Address 17h < \Delta current value for G2 LED current step >

BIT	Name	Initial				Fur	nctior	า			
DII	Name	milla		0					1		
D7	-	-		-					-		
D6	-	-		-					-		
D5	IDLTG2LED5	0									
D4	IDLTG2LED4	0	IDLTG2	IDLTG2	IDLTG2	IDLT	G2	IDLTG2	IDLTG2	Current	
04		0	LED5	LED4	LED3	LED)2	LED1	LED0	value	
D3	IDLTG2LED3	0	0	0	0	0		0	0	0mA	
D2	IDLTG2LED2	0	0	0	0	0		0	1	0.5mA	
D1	IDLTG2LED1	0	0	0	0	0		1	0	1mA	
D0	IDLTG2LED0	0	•	•	•	•		•	•		
			•	•	•	•		•	•	0.5mA	
			•	•	•	•		•	•	Step	
			•	•	•	•		•	•		
			1	1	1	1		0	1	30.5mA	
			1	1	1	1		1	0	31mA	
			1	1	1	1		1	1	31.5mA	
			When $120k\Omega$ is connected to ISET pin.								

Address 18h <B2 LED current value1>

BIT	Name	Initial	Function							
		miliai	0				1			
D7	-	-	-				-			
D6	-	-		-			-			
D5	I1B2LED5	0		-			r	P		
D4	I1B2LED4	0	I1B2LED5	I1B2LED4	I1B2LED3	I1B2LED2	I1B2LED1	I1B2LED0	Current value	
D3	I1B2LED3	0	0	0	0	0	0	0	0mA	
D2	I1B2LED2	0	0	0	0	0	0	1	0.5mA	
D1	I1B2LED1	0	0	0	0	0	1	0	1mA	
D0	I1B2LED0	0	•	•	•	•	•	•		
			•	•	•	•	•	•	0.5mA	
			•	•	•	•	•	•	Step	
			•	•	•	•	•	•		
			1	1	1	1	0	1	30.5mA	
			1	1	1	1	1	0	31mA	
			1	1	1	1	1	1	31.5mA	
			When $120k\Omega$ is connected to ISET pin.							

Address 19h <Δ current value for B2 LED current step >

BIT	Name	Initial	Function								
DII	Iname	miliai			0					1	
D7	-	-	-					-			
D6	-	-			-			-			
D5	IDLTB2LED5	0	_								
D4	IDLTB2LED4	0		IDLTB2	IDLTB2	IDLTB2	IDL	TB2	IDLTB2	IDLTB2	Current value
04	IDEI DZEED4	0		LED5	LED4	LED3	LE	D2	LED1	LED0	Current value
D3	IDLTB2LED3	0		0	0	0	()	0	0	0mA
D2	IDLTB2LED2	0		0	0	0	()	0	1	0.5mA
D1	IDLTB2LED1	0		0	0	0	()	1	0	1mA
D0	IDLTB2LED0	0		•	•	•	•	•	•	•	
				•	•	•	•	•	•	•	0.5mA
				•	•	•		•	•	•	Step
				•	•	•		•	•	•	
				1	1	1		1	0	1	30.5mA
				1	1	1		1	1	0	31mA
				1	1	1		1	1	1	31.5mA
			When $120k\Omega$ is connected to ISET pin.								

Address 1Ah <RGB1, RGB2 LED external ON/OFF control>

DIT				Function				
BIT	Name	Initial		0			1	
D7	-	-	-			-		
D6	-	-		-		-		
D5	-	-		-		-		
D4	-	-		-		-		
D3	-	-		-		-		
D2	-	-	-			-		
D1	RGB2MEL	0						
D0	RGB1MEL	0		RGB*MEL RGB*CNT (external pin)	RGB* LED Lighting	
			0	L		ON		
				0	Н		ON	
				1	L		OFF	
				1		H ON		
				But, a state of lig	hting depends	on the setup o	f other registers.	

RGB LED Operating

1. Operating mode

RGB LED can set up the following operating mode by the setup of the register.

< Setup register >

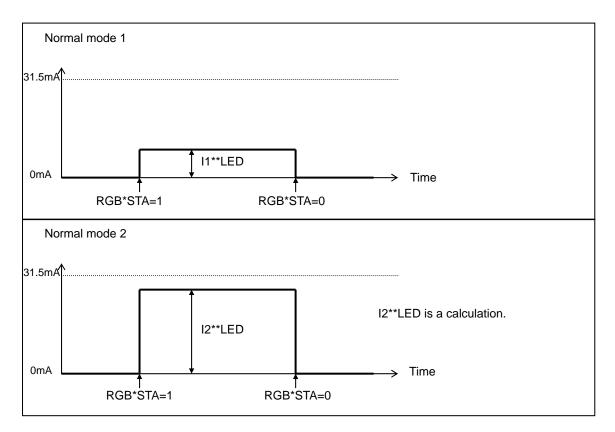
I1**LED : (register) Initial electric current value [mA] IDLT**LED : (register) The electric current Δ value of around 1Step [mA] RGB*SLNUM : (register) slope step number (1,2,4,8,16,32,64 Step) RGB*SL1STEP : (register) The first half slope 1Step time [ms] RGB*SL2STEP : (register) The latter half slope 1Step time [ms] RGB*WT1TM : (register) The first half lighting time [ms] RGB*WT2TM : (register) The latter half lighting time [ms]

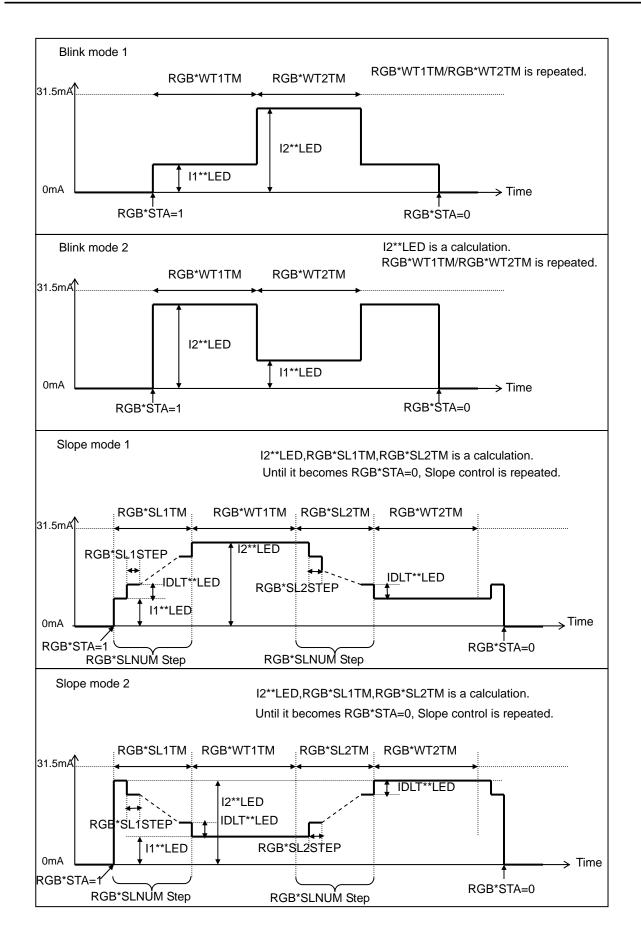
As for the following setup, calculate it from the above setup. I2**LED : At the time of middle lighting current value [mA] = I1**LED + IDLT**LED x RGB*SLNUM (In case of the value that a calculation exceeds maximum value, the current value is at the limit with maximum.) RGB*SL1TM : The first half slope time [ms] = RGB*SL1STEP x RGB*SLNUM RGB*SL2TM : The latter half slope time [ms] = RGB*SL2STEP x RGB*SLNUM

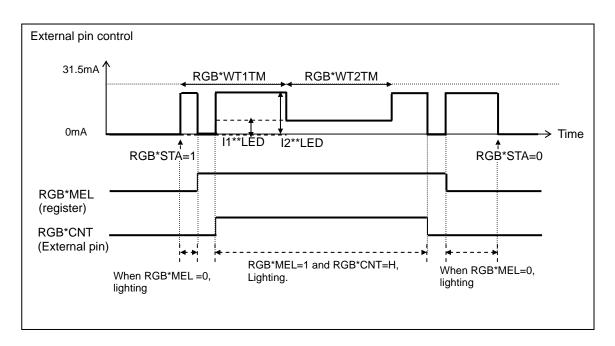
Each setup is necessary for DC current (at Normal mode or Blink mode).

(* : 1/ 2 channels is shown. ** : R1/G1/B1/R2 /G2/B2 is shown.)

Note) The current value in the table, it is value when $120k\Omega$ is connected to ISET pin.

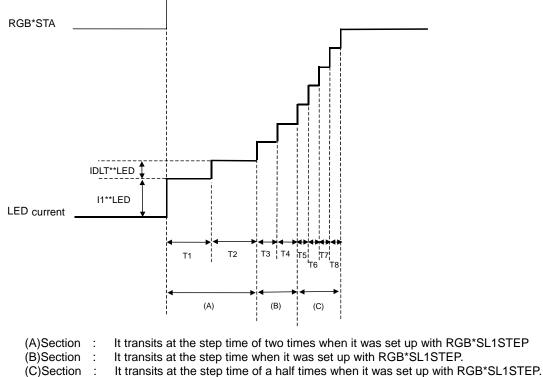






2. Slope control

The slope control that this LSI is equipped processes step time inside as follows. It is made to have electric current by the log curve that is a simple target as to the slope.



The time of the total (RGB*SL1TM) is calculated with RGB*SL1STEP x RGB*SLNUM.

A similar movement is done on the descent (RGB*SL2TM) side as well.

The acceptance of the setup of a register concerned with LED working during the slope movement stops. But, a RGB*STA signal interrupts even during the slope movement, and it is possible that LED is turned off.

Explanation for Operate

1. Reset

- There are two kinds of reset, software reset and hardware reset.
- (1) Software reset
 - \cdot All the registers are initialized more than making a register (SFTRST) setup "1".
 - The register of software resetting is an automatic return (Auto Return 0).
- (2) Hardware reset
 - It shifts to hardware reset by changing RESET pin "H" \rightarrow "L".
 - The condition of all the registers under hardware reset pin is returned to the initial value, and it stops accepting all address.
 - It's possible to release from a state of hardware reset by setting register "L" \rightarrow "H".
 - RESET pin has delay circuit. It doesn't recognize as hardware reset in "L" period under 5µs.
- (3) Reset Sequence

• When hardware reset was done during software reset, software reset is canceled when hardware reset is canceled. (Because the initial value of software reset is "0")

2. Thermal shutdown

The blocks which thermal shutdown function is effective in the following.

Charge pump LED Driver REG1

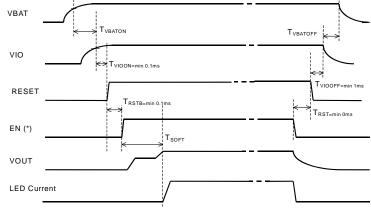
REG2 is not shut down by thermal shutdown function, because REG2 can be used for I/O voltage.

A thermal shutdown function works in about 195 . Detection temperature has a hysteresis, and detection release temperature is about 175 (Design reference value)

3. DC/DC

Start up

DC/DC circuit operates when either LED turns ON. (But, when LED connection is set to DC/DC output (VOUT) only.) DC/DC circuit has soft start function to prevent a rush current. VBAT and VIO sequence is as follow.



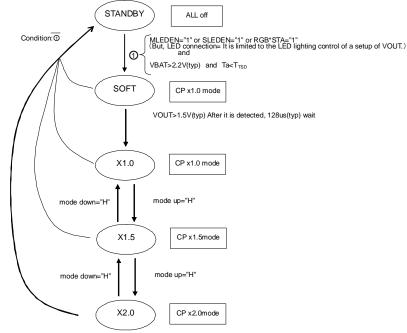
(*) An EN signal means the following in the upper figure. EN = "MLEDEN" or "SLEDEN" or "RGB1STA" or "RGB2STA"

(= LED The LED lighting control of a setup of connection VOUT)

But, as for VBAT < 2.2V (typ) or Ta > T_{TSD} (typ : 195° C), a protection function functions, and an EN signal doesn't become effective.

Mode transition

The transition of boosts multiple transits automatically by the VBAT voltage and the voltage of the LED electric current inflow pin.



Over voltage protection / Over current protection

DC/DC circuit output (VOUT) is equipped with the over-voltage protection and the over current protection function. A VOUT over-voltage detection voltage is about 6.0V.(VOUT at the time of rise in a voltage) A detection voltage has a hysteresis, and a detection release voltage is about 5.75V. (Design reference value) And, when VOUT output short-circuits in GND, drain electric current is controlled by an over current protection function.

4. LED Driver

LED current value setting

LED maximum current value (White LED driver and RGB LED Driver common) can be established in the resistance value RISET that it is connected to the ISET Pin.

A setting is shown in the following.

ILEDmax = 6.4 x 0.6 [V] / RISET [kΩ]	[A]	(Typ)	MLED1to4, SLED1to2
ILEDmax = 6.3 x 0.6 [V] / RISET [kΩ]	[A]	(Typ)	All RGB LED

The maximum setting of LED current is 32mA (MLED and SLED), 31.5mA (RGB) on the D range of the internal circuit.

LED current overload protection

ISET Pin is mount with the GND short detection function. LED current value prevents excessive LED current from flowing when ISET Pin becomes low impedance because it is shown with a formula of the former extension.

White LED Driver

The number of lighting of white LED can be set up by the register MLEDSEL and SLEDSEL (address02h).

The settlement of the number of lighting can be setup with follow.

Main LCD Back light ••• 3 Light (MLED1 to 3) or 4 Light (MLED1 to 4)

Sub LCD Back light •••1 Light (SLED1) or 2 Light (SLED1 to 2)

Connect the LED pin that isn't used to the ground.

RGB LED Driver

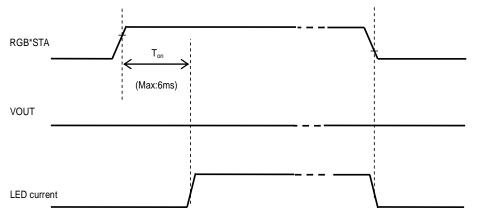
By register B*LEDMD and G*LEDMD (address05h), a place of connection of Green LED and Blue LED It can be set up in VBAT or VOUT. When Vf is low, it is connected to VBAT, and it is possible that efficiency is raised.

When a VBAT connection is chosen, a feedback route to the DC/DC circuit is interrupted, and it works as a simple constant current driver.

A write protect is given in the following address when "1" is written in the RGB*STA register.

Register	A protected address		
RGB1STA	06h to 0Fh		
RGB2STA	10h to 19h		

VBAT connection a start in the setup Sequence

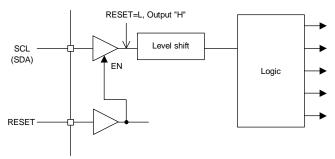


When the connection of LED is VBAT, only a LED driver turns it on, and a DC/DC circuit is turned off. The LED pin which isn't used is to short to the ground.

But, the setup of a register concerned with LED that isn't used is prohibited.

5. I/O

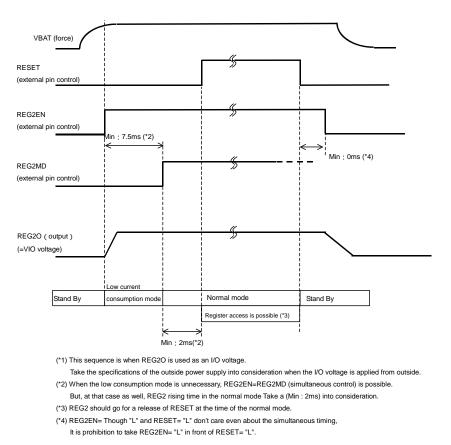
CPU interface control input is possible low voltage interface. Interface peripheral block diagram is as follows. VIO voltage or interface voltage is possible the setting range of 1.65 to 3.3V. (But, VBAT voltage \geq VIO voltage) Also, I/O of with enable is being used for SCL, SDA input as a prevention of clock propagation to the inside when other LSI shared the SCL, SDA line.



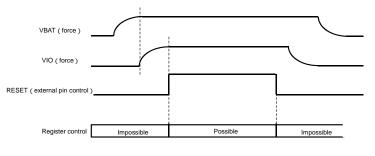
An equivalent circuit around the part I/O becomes p.8. By rising turn of the I/O power supply and the input level be careful enough because an electric current route may occur through the protection Diode of the pin.

6. About the start of REG2 (the voltage for I/O)

It must start as follows when REG2 output is used as VIO voltage.



It must start as follows when external power supply is used as VIO voltage.

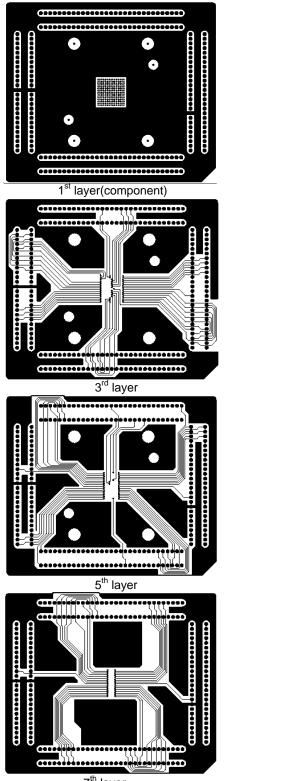


VIO should go for a release of RESET after the time of the rising mode.
And it is forbid to fall VIO before RESET="L".

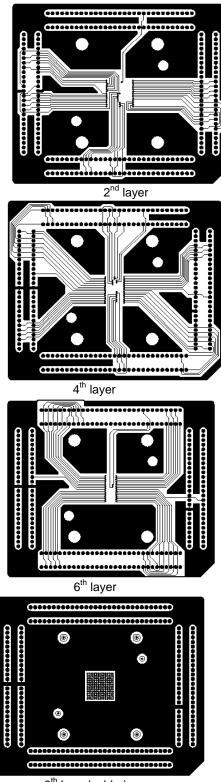
7. About the pin management of the function that isn't used and test pins Please connect the pin that isn't used and test pin referred to equivalent circuit (P.6).

> TESTI1, TESTI2 •••••• Short to GND (Must) because input pin for test TESTO1, TESTO2 •••••• Be OPEN because output for test T1 to T4 •••••• Short to GND (Must) because input pin for test Non-used LED Pin •••• Short to GND But, the setup of a register concerned with LED that isn't used is prohibited. REG2EN, REG2MD, RGB1CNT, RGB2CNT •••••• Pull-Down resistance is built in. Short to GND

8. BD6081GU PCB pattern of the Power dissipation measuring board

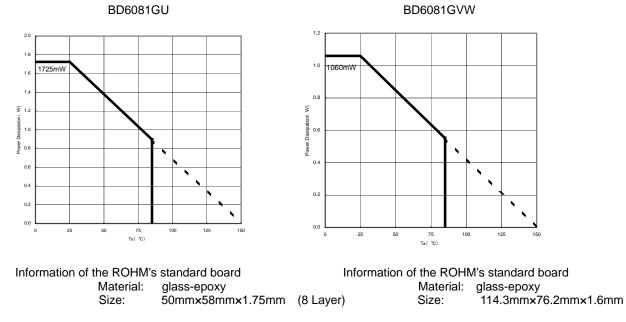


7th layer



8th layer(solder)

Power dissipation (On the ROHM's standard board)



Pattern of the board: Refer to page 30.

Operational Notes

(1) Absolute Maximum Ratings

An excess in the absolute maximum ratings, such as supply voltage, temperature range of operating conditions, etc., can break down devices, thus making impossible to identify breaking mode such as a short circuit or an open circuit. If any special mode exceeding the absolute maximum ratings is assumed, consideration should be given to take physical safety measures including the use of fuses, etc.

(2) Power supply and ground line

Design PCB pattern to provide low impedance for the wiring between the power supply and the ground lines. Pay attention to the interference by common impedance of layout pattern when there are plural power supplies and ground lines. Especially, when there are ground pattern for small signal and ground pattern for large current included the external circuits, please separate each ground pattern. Furthermore, for all power supply pins to ICs, mount a capacitor between the power supply and the ground pin. At the same time, in order to use a capacitor, thoroughly check to be sure the characteristics of the capacitor to be used present no problem including the occurrence of capacity dropout at a low temperature, thus determining the constant.

(3) Ground voltage

Make setting of the potential of the ground pin so that it will be maintained at the minimum in any operating state. Furthermore, check to be sure no pins are at a potential lower than the ground voltage including an actual electric transient.

(4) Short circuit between pins and erroneous mounting

In order to mount ICs on a set PCB, pay thorough attention to the direction and offset of the ICs. Erroneous mounting can break down the ICs. Furthermore, if a short circuit occurs due to foreign matters entering between pins or between the pin and the power supply or the ground pin, the ICs can break down.

(5) Operation in strong electromagnetic field

Be noted that using ICs in the strong electromagnetic field can malfunction them.

(6) Input pins

In terms of the construction of IC, parasitic elements are inevitably formed in relation to potential. The operation of the parasitic element can cause interference with circuit operation, thus resulting in a malfunction and then breakdown of the input pin. Therefore, pay thorough attention not to handle the input pins, such as to apply to the input pins a voltage lower than the ground respectively, so that any parasitic element will operate. Furthermore, do not apply a voltage to the input pins when no power supply voltage is applied to the IC. In addition, even if the power supply voltage is applied, apply to the input pins a voltage lower than the gover than the power supply voltage or within the guaranteed value of electrical characteristics.

(7) External capacitor

In order to use a ceramic capacitor as the external capacitor, determine the constant with consideration given to a degradation in the nominal capacitance due to DC bias and changes in the capacitance due to temperature, etc.

(8) Thermal shutdown circuit (TSD)

This LSI builds in a thermal shutdown (TSD) circuit. When junction temperatures become detection temperature or higher, the thermal shutdown circuit operates and turns a switch OFF. The thermal shutdown circuit, which is aimed at isolating the LSI from thermal runaway as much as possible, is not aimed at the protection or guarantee of the LSI. Therefore, do not continuously use the LSI with this circuit operating or use the LSI assuming its operation.

(9) Thermal design

Perform thermal design in which there are adequate margins by taking into account the permissible dissipation (Pd) in actual states of use.

(10) LDO

Use each output of LDO by the independence. Don't use under the condition that each output is short-circuited because it has the possibility that an operation becomes unstable.

(11) About the pin for the test, the un-use pin

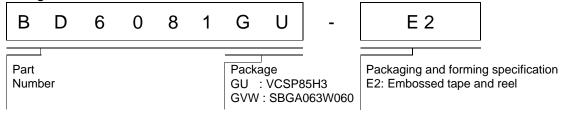
Prevent a problem from being in the pin for the test and the un-use pin under the state of actual use. Please refer to a function manual and an application notebook. And, as for the pin that doesn't specially have an explanation, ask our company person in charge.

Status of this document

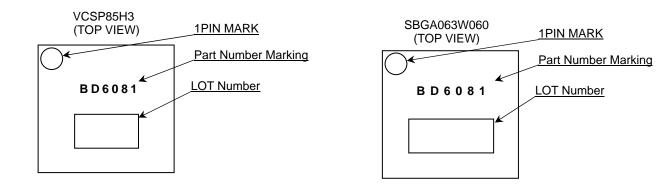
The Japanese version of this document is formal specification. A customer may use this translation version only for a reference to help reading the formal version.

If there are any differences in translation version of this document formal version takes priority.

Ordering Information

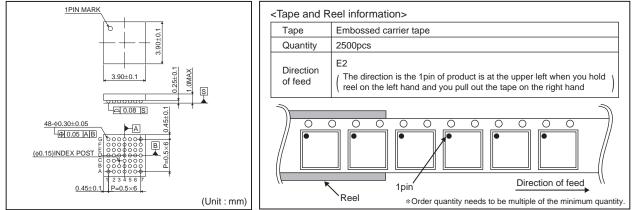


Marking Diagrams

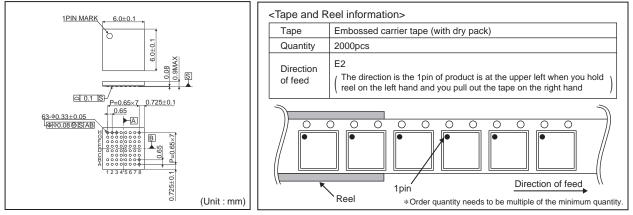


Physical Dimensions Tape and Reel Information

VCSP85H3 (BD6081GU)



SBGA063W060



Revision History

Date	Revision	Changes
28.Sep.2012	001	New Release

Notice

Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment ^(Note 1), transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

JAPAN	USA	EU	CHINA	
CLASSⅢ		CLASS II b		
CLASSⅣ	CLASSⅢ	CLASSⅢ	CLASSⅢ	

- 2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
 - [a] Installation of protection circuits or other protective devices to improve system safety
 - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
- 3. Our Products are designed and manufactured for use under standard conditions and not under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
 - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
 - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
 - [C] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

Precaution for Electrostatic

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
 - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

Precaution for Product Label

QR code printed on ROHM Products label is for ROHM's internal use only.

Precaution for Disposition

When disposing Products please dispose them properly using an authorized industry waste company.

Precaution for Foreign Exchange and Foreign Trade act

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

Precaution Regarding Intellectual Property Rights

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